

50 AMP SILICON BRIDGE RECTIFIERS

FEATURES

- VOID FREE VACUUM DIE SOLDERING FOR MAXIMUM MECHANICAL STRENGTH AND HEAT DISSIPATION (Solder Voids: Typical < 2%, Max. < 10% of Die Area)
- **BUILT-IN STRESS RELIEF MECHANISM FOR** SUPERIOR RELIABILITY AND PERFORMANCE
- INTEGRALLY MOLDED HEAT SINK PROVIDES VERY LOW THERMAL RESISTANCE FOR MAXIMUM HEAT DISSIPATION

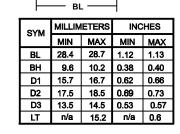
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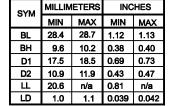
MECHANICAL DATA

- Case: Molded plastic, U/L Flammability Rating 94V-0
- Terminals: Round silver plated copper pins or fast-on terminals
- Soldering: Per MIL-STD 202 Method 208 guaranteed
- Polarity: Marked on side of case
- Mounting Position: Any. Through hole for #8 screw. Max. mounting torque = 20 in-lb.
- Weight: Fast-on Terminals 0.7 Ounces (20.0 Grams) Wire Leads - 0.55 Ounce (16.0 Grams)

Suffix "P" indicates molded PLASTIC with integrally mounted Heat Sink Heat Sink Т BH вн LT LL Body HOLE FOR #8 SCREW Top View of Heat Sink HOLE FOR #8 SCREW _" LD AC AC ÷ D1 Т BL BL D1 D3 D2 AC - D2 – D1 – ŀ н -

MECHANICAL SPECIFICATION SERIES: DB5000P - DB5010P and ADB5004P - ADB5008P





BL

Suffix "T" indicates FAST-ON TERMINALS

Suffix "W" indicates WIRE LEADS

MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive loads, derate current by 20%.

| PARAMETER (TEST CONDITIONS) | | RATINGS | | | | | | | | | | |
|--|-----------|---|------|--------------|-----------------------------|-----|-----|-----|-------------|-------------|--------------------|-------|
| | SYMBOL | | ALAN | | NON-CONTROLLED AVALANCHE | | | | | | UNITS | |
| Series Number | | | | ADB 5008P | | | | | DB 5006P | DB 5008P | DB 5010P | |
| Maximum DC Blocking Voltage | Vrм | 400 | 600 | 800 | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | VOLTS |
| Working Peak Reverse Voltage | Vrwm | | | | | | | | | | | |
| Maximum Peak Recurrent Reverse Voltage | Vrrm | | | | | | | | | | | |
| RMS Reverse Voltage | VR (RMS) | 280 | 420 | 560 | 35 | 70 | 140 | 280 | 420 | 560 | 700 | |
| Mimimum Avalanche Voltage | V(BR) Min | See Note 1 | | | n/a | | | | | | | VOLTS |
| Maximum Avalanche Voltage | V(BR) Max | See Note 1 | | | n/a | | | | | | | |
| Forward Voltage Drop (Per Diode) at 25 Amps DC Ma | | 1.00 1.05 1.00 1.05 0.95 1.00 0.95 1.00 | | | | | | | | | | |
| Rating for Fusing (Non-repetitive; 1mS < t < 8.3mS | l²t | 1000 | | | | | | | | | A ² SEC | |
| Peak Forward Surge Current. Single 60Hz Half-Sine Wave Superimposed on Rated Load (JEDEC Method). TJ = 175° C | Ігѕм | 600 | | | | | | | | | | AMPS |
| Average Forward Rectified Current @ Tc = 55° C | lo | 50 | | | | | | | | | | |
| Junction Operating and Storage Temperature Range | ТЈ, ТЅТС | -55 to +175 | | | | | | | | | | °C |
| Maximum Reverse Current at Rated VRM @ TA = 25 @ TA = 125 | - DM | 1 50 | | | | | | | | | | μΑ |
| Minimum Insulation Breakdown Voltage (Circuit to Case) | Viso | 2500 | | | | | | | | | | VOLT |
| Typical Thermal Resistance, Junction to Case | Rejc | 1.10 | | | | | | | | | °C/W | |

Notes: (1) These Bridges Exhibit The Avalanche Characteristic at Breakdown. If Your Application Requires a Specific Breakdown Voltage Range, Please Contact Us.



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RATING & CHARACTERISTIC CURVES FOR SERIES DB5000P - DB5010P and SERIES ADB5004P - ADB5008P

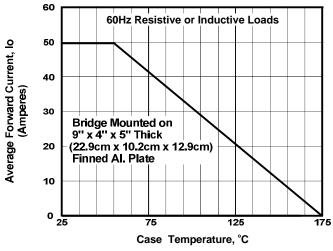
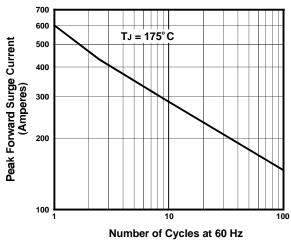
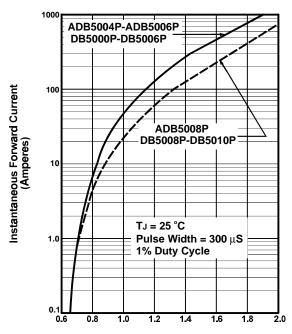


FIGURE 1. FORWARD CURRENT DERATING CURVE







Instantaneous Forward Voltage (Volts) FIGURE 3. TYPICAL FORWARD CHARACTERISTIC PER DIODE

